

Characterization of Dislocations in Single-Crystalline Ag₃Sn Intermetallic Alloys

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The intermetallic compound Ag₃Sn is an important component phase present in both dental amalgams [1] and lead-free solders for microelectronic applications [2]. Ag₃Sn exhibits the D0_a Cu₃Ti-type structure, which is an ordered orthorhombic form of the HCP structure [3]. The phase is unusually ductile for an intermetallic compound, but there have been very few studies on the defects and deformation mechanisms in Ag₃Sn due to the difficulty of making high quality single phase samples [4]. Early studies [3] suggested that deformation in Ag₃Sn can proceed by {011}-type twinning, and this is consistent with the results of micro-hardness indentation studies [5]. In a recent study [6] we characterized defect structures in a Ag₃Sn-Cu₃Sn pseudo-binary alloy deformed in compression. A high density of dislocations was generated in the Ag₃Sn grains, but no deformation twinning was observed. However, the character of these dislocations was not analyzed in detail. In the present study, we have examined the dislocations structures in deformed single-crystal Ag₃Sn and the operative deformation mechanisms were considered.

Single-phase Ag₃Sn crystals several millimeters in size were produced by a solution growth method [7]. The single-crystal specimens were deformed by bending at room temperature, and the microstructures of the deformed crystals were evaluated using transmission electron microscopy (TEM). Cross-sectional TEM specimens through the (001) free surface were prepared using an FEI Helios Nanolab 460F1 dual-beam focused ion beam (FIB) instrument following the procedures described by Yu et al. [4]. The TEM specimens were examined in an FEI Talos F200X S/TEM operating at accelerating voltage of 200 kV.

The deformed Ag₃Sn crystals contained both twins and dislocations, and particular attention was paid to the character of the dislocations. Figure 1 is a bright-field (BF) TEM image from a typical area in deformed Ag₃Sn taken under two-beam conditions with $\mathbf{g} = 040$, where \mathbf{g} is the reciprocal lattice vector of the diffracting planes. The beam direction is close to [100]. Many parallel dislocations are present, and these extend for up to 1.5 μm within the specimen volume. The average dislocation density was calculated as $\rho = 10^9\text{-}10^{10} \text{ cm}^{-2}$ based on such images. The Burgers vectors, \mathbf{b} , were determined by diffraction contrast analyses using the $\mathbf{g} \cdot \mathbf{b} = 0$ criterion, and it was found all the segments are edge dislocations having Burgers vectors, \mathbf{b} , parallel to [010]. Since the line directions of the defects are approximately [001], this is consistent with deformation on the [010](100) slip system. It is noted that most of the dislocations were present as dislocation pairs, with a separation of up to 30 nm. To determine if these paired dislocations are partial dislocations or dislocation dipoles, BF TEM images were taken with $\pm\mathbf{g}$ ($\mathbf{g} = 040$), as presented in Figure 2. Significant changes in spacing between these dislocation pairs were noticed on reversing the sign of \mathbf{g} . This inside/outside contrast reveals that these dislocation pairs are actually dipoles. Such dipoles are probably formed by two dislocations with opposite Burgers vectors (i.e. [010] and $[0\bar{1}0]$) gliding in opposite directions on adjacent (100) planes and being trapped when their strain fields interact. We note that this slip system has not been reported previously for any D0_a phase, and the activation of this system in addition to twinning could help to explain the extraordinary ductility exhibited by the Ag₃Sn phase [8].

References:

- [1] TK Hooghan *et al*, *J. Mater. Res.* **11** (1996) p. 2474.
 [2] K Sugauma, *Curr. Opin. Solid State Mater. Sci.* **5** (2001) p. 55.
 [3] CW Fairhurst and JB Cohen, *Acta Cryst.* **B28** (1972) p. 371.
 [4] H Yu *et al*, *J. Mater. Sci.* **51** (2016) p. 6474.
 [5] G Ghosh, *J. Mater. Res.* **19** (2004) p. 1439.
 [6] Y Sun *et al*, *J. Mater. Sci.* **52** (2017) p. 2944.
 [7] PC Canfield and Z Fisk, *Philos. Mag.* **65** (1992) p. 1117.
 [8] The microscopy studies were performed in the UConn/FEI Center for Advanced Microscopy and Materials Analysis (CAMMA).

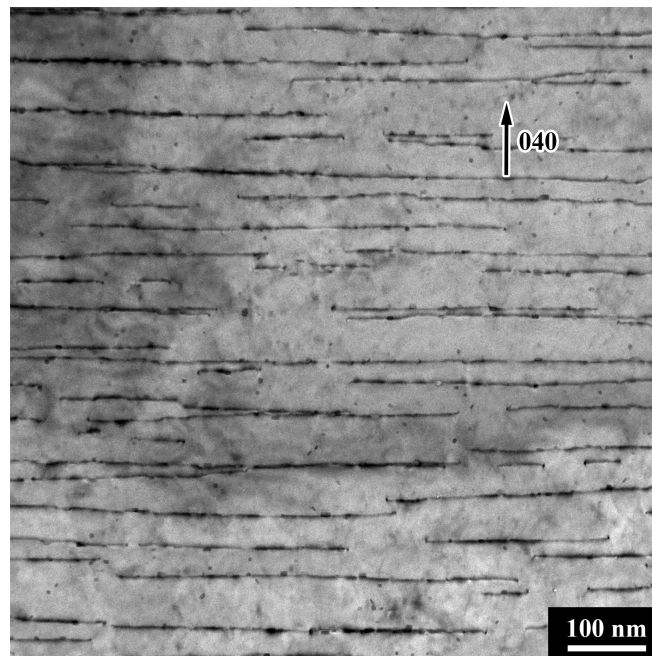


Figure 1. Bright-field TEM image of [010] dislocations in deformed single-crystalline Ag_3Sn taken under two beam conditions with $\mathbf{g} = 040$, beam direction close to [100].

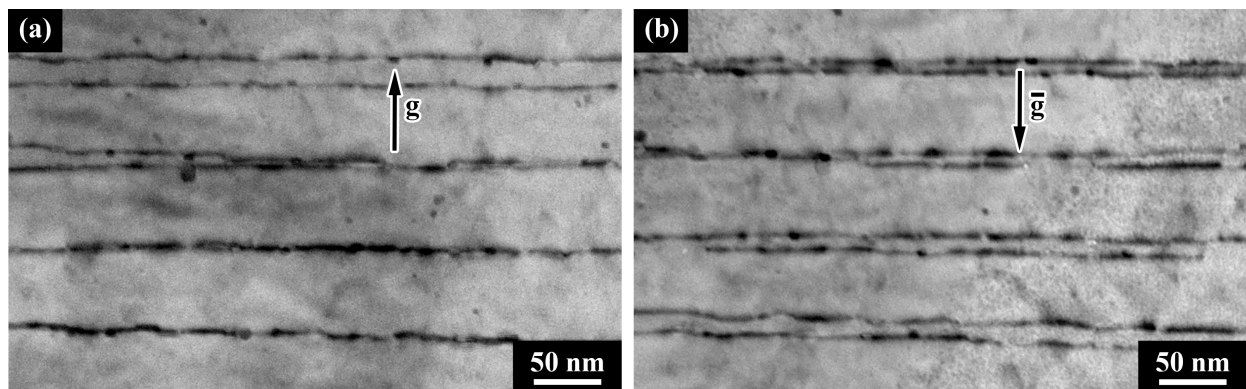


Figure 2. Images of dislocation dipoles showing inside/outside contrast on reversing $\mathbf{g} (\pm 040)$.